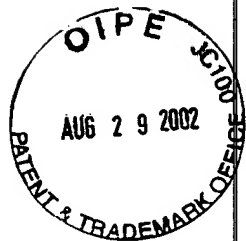


IN THE UNITED STATES PATENT AND TRADEMARK OFFICE



#4/Amend B
9/2nd
RECEIVED
SEP-9 2002
TECHNOLOGY CENTER 2800

Applicant(s): Halahan, Patrick B.; Siniaguine, Oleg
Assignee: Tru-Si Technologies, Inc.
Title: Semiconductor Structures Having Multiple Conductive Layers By An Opening, And Methods For Fabricating Same
Application No.: 09/941,447 Filing Date: 08/28/2001
Examiner: Thomas, Toniae M. Group Art Unit: 2822
Docket No.: M-9999-1D US

San Jose, California
29 August 2002

COMMISSIONER FOR PATENTS
Washington, D.C. 20231

AMENDMENT

Sir:

Responsive to the Office Action mailed 5 June 2002, please amend the above patent application as follows:

09/06/2002 G6EBREGI 00000026 192386 09941447
01 FC:103 828.00 CH

IN THE TITLE

Before "SEMICONDUCTOR STRUCTURES" insert --FABRICATION OF--;
delete ", AND METHODS FOR FABRICATING SAME".

IN THE SPECIFICATION

Page 1, amend the paragraph beginning at line 14 to read

LAW OFFICES OF
SKJERVEN MORRILL LLP
25 METRO DRIVE, SUITE 700
SAN JOSE, CA 95110
(408) 433-9200
FAX (408) 433-7500

--According to some aspects of the invention, a circuit manufacturing method comprises: